

## Vishay General Semiconductor

## Surface-Mount TMBS® (Trench MOS Barrier Schottky) Rectifier

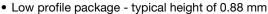


#### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2.0 A			
V <sub>RRM</sub>	150 V			
I <sub>FSM</sub>	50 A			
$V_F$ at $I_F = 1.0$ A $(T_J = 125  ^{\circ}C)$	0.56 V			
T <sub>J</sub> max.	175 °C			
Package	DFN3820A			
Circuit configuration	Single			

#### **FEATURES**





- Trench MOS Schottky technology
- · Low power losses, high efficiency
- Low forward voltage drop
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

RoHS COMPLIANT HALOGEN FREE

- AEC-Q101 qualified available
  - Automotive ordering code; base P/NHM3
- Compatible to SMP (DO-220AA) package case outline
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

#### TYPICAL APPLICATIONS

For use in low voltage, high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

#### **MECHANICAL DATA**

Case: DFN3820A

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 -

halogen-free, RoHS-compliant, and AEC-Q101 qualified

leads, solderable

Terminals: matte tin plated J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V2NM153	UNIT	
Device marking code		2MP		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	150	V	
Maximum avarage featured restified autrent (fig. 1)	I <sub>F(AV)</sub> (1)	2	Α	
Maximum average forward rectified current (fig. 1)	I <sub>F(AV)</sub> (2)	1.7	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	50	А	
Operating junction and storage temperature range	T <sup>J</sup> (3)	-40 to +175	°C	
Operating junction and storage temperature range	T <sub>STG</sub>	-55 to +175	°C	

- (1) Mounted on 10 mm x 10 mm copper pad area PCB
- (2) Free air, mounted on FR4 PCB, 2 oz., standard footprint
- (3) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta,JA}$



#### www.vishay.com

## Vishay General Semiconductor

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage	I <sub>F</sub> = 1.0 A	T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.71	-	V
	$I_F = 2.0 \text{ A}$			0.88	0.97	
	I <sub>F</sub> = 1.0 A	- T <sub>J</sub> = 125 °C		0.56	-	
	$I_F = 2.0 \text{ A}$			0.63	0.68	
Reverse current	V <sub>R</sub> = 100 V	T <sub>J</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	0.0002	ı	
		T <sub>J</sub> = 125 °C		0.4	-	mA
	V <sub>R</sub> = 150 V	T <sub>J</sub> = 25 °C		-	0.02	IIIA
		T <sub>J</sub> = 125 °C		0.8	2.0	
Typical junction capacitance	4.0 V, 1 MHz		CJ	110	-	pF

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise specified)					
PARAMETER	SYMBOL	TYP.	MAX.	UNIT	
Thermal resistance	R <sub>0</sub> JA (1)(2)	140	175	°C/W	
Thermal resistance	R <sub>0JM</sub> (3)	6	7.5		

#### Notes

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

(2) Thermal resistance junction-to-ambient to follow JEDEC® 51-2A, device mounted on FR4 PCB, 2 oz., standard footprint

(3) Thermal resistance junction-to-mount to follow JEDEC 51-14 transient dual interface test method (TDIM)

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
V2NM153-M3/H	0.023	Н	3500	7" diameter plastic tape and reel	
V2NM153-M3/I	0.023	I	14 000	13" diameter plastic tape and reel	
V2NM153HM3/H (1)	0.023	Н	3500	7" diameter plastic tape and reel	
V2NM153HM3/I (1)	0.023	I	14 000	13" diameter plastic tape and reel	

#### Note

(1) AEC-Q101 qualified

## Vishay General Semiconductor

## **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

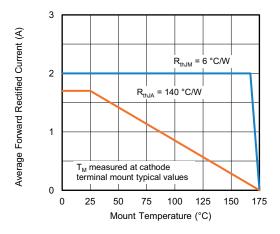


Fig. 1 - Maximum Forward Current Derating Curve

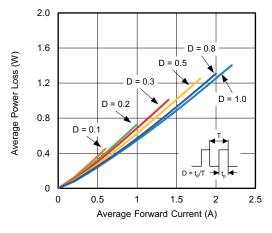


Fig. 2 - Forward Power Loss Characteristics

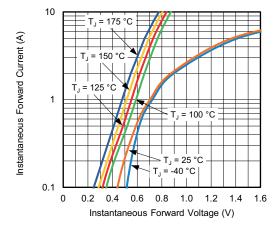


Fig. 3 - Typical Instantaneous Forward Characteristics

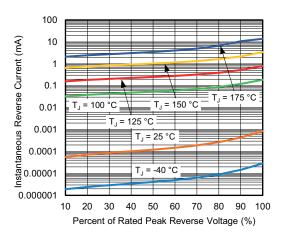


Fig. 4 - Typical Reverse Characteristics

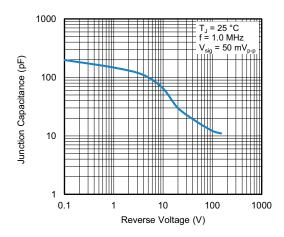


Fig. 5 - Typical Junction Capacitance

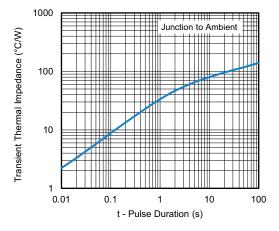


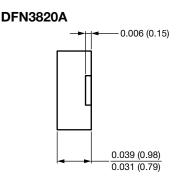
Fig. 6 - Typical Transient Thermal Impedance

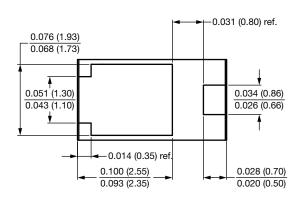


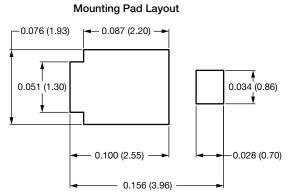
## Vishay General Semiconductor

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

# 









## **Legal Disclaimer Notice**

Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.